

BCR25CM-12LB

600V - 25A - Triac

Medium Power Use

R07DS1152EJ0100 Rev.1.00 Jan 29, 2014

Features

• $I_{T (RMS)} : 25 A$ V_{DRM} : 600 V

I_{FGT I}, I_{RGT I}, I_{RGT III}: 50 mA

Tj: 150 °C

Planar Passivation Type

Non-Insulated Type

Outline

RENESAS Package code: PRSS0004AG-A (Package name: TO-220AB)





- T₁ Terminal
 T₂ Terminal
- 3. Gate Terminal
- 4. T₂ Terminal

Applications

Vacuum cleaner, electric heater, light dimmer, copying machine, and other general controlling devices

Maximum Ratings

| Dovometer | Cumbal | Voltage class | Unit |
|--------------------------------------------------------|-----------|---------------|------|
| Parameter | Symbol | 12 | Unit |
| Repetitive peak off-state voltage ^{Note1} | V_{DRM} | 600 | V |
| Non-repetitive peak off-state voltage ^{Note1} | V_{DSM} | 720 | V |

| Parameter | Symbol | Ratings | Unit | Conditions |
|--------------------------------|----------------------|-------------|------------------|---------------------------------------------------------------------------|
| RMS on-state current | I _{T (RMS)} | 25 | А | Commercial frequency, sine full wave 360°conduction, Tc = 115°C Note3 |
| Surge on-state current | I _{TSM} | 250 | A | 50 Hz sinewave 1 full cycle, peak value, non-repetitive |
| I ² t for fusion | l ² t | 313 | A ² s | Value corresponding to 1 cycle of half wave 50 Hz, surge on-state current |
| Peak gate power dissipation | P_{GM} | 5 | W | |
| Average gate power dissipation | P _{G (AV)} | 0.5 | W | |
| Peak gate voltage | V_{GM} | 10 | V | |
| Peak gate current | I _{GM} | 2 | Α | |
| Junction Temperature | Tj | -40 to +150 | °C | |
| Storage temperature | Tstg | -40 to +150 | °C | |
| Mass | _ | 2.1 | g | Typical value |

Electrical Characteristics

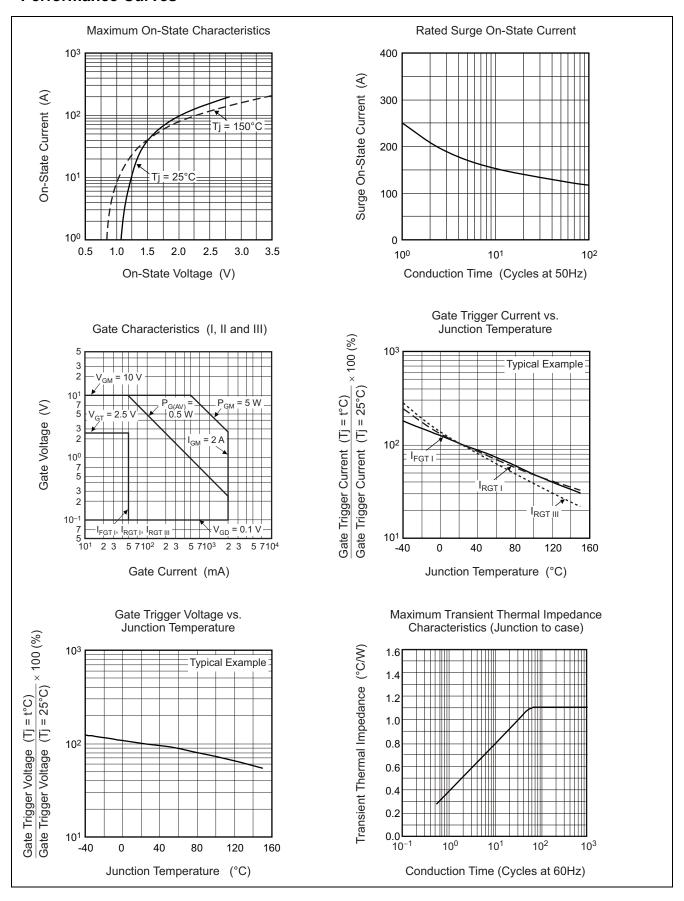
| Parameter | | Symbol | Rated value | | | Unit | Test conditions | |
|---------------------------------------|-----------------------------------|-----------------------|-------------|------|------|------|----------------------------------------------------------------|--|
| | | Symbol | Min. | Тур. | Max. | Unit | rest conditions | |
| Repetitive peak off-state cui | Repetitive peak off-state current | | _ | _ | 3.0 | mA | Tj = 125°C, V _{DRM} applied | |
| | | | _ | _ | 5.0 | | Tj = 150°C, V _{DRM} applied | |
| On-state voltage | | V _{TM} | _ | _ | 1.5 | V | Tc = 25°C, I _{TM} = 40A, instantaneous measurement | |
| Gate trigger voltage ^{Note2} | I | V_{FGTI} | _ | _ | 2.0 | V | $Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω, | |
| | II | V_{RGTI} | _ | _ | 2.0 | V | $R_G = 330 \Omega$ | |
| | III | V_{RGTIII} | _ | _ | 2.0 | V | | |
| Gate trigger curent ^{Note2} | I | I_{FGTI} | _ | _ | 50 | mA | $Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω, | |
| | II | I_{RGTI} | _ | _ | 50 | mA | $R_G = 330 \Omega$ | |
| | III | I _{RGTIII} | _ | _ | 50 | mA | | |
| Gate non-trigger voltage | | V_{GD} | 0.2 | _ | _ | V | $Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$ | |
| | | | 0.1 | _ | _ | V | $Tj = 150^{\circ}C, V_D = 1/2 V_{DRM}$ | |
| Thermal resistance | | R _{th (j-c)} | _ | _ | 1.1 | °C/W | Junction to case ^{Note3, Note4} | |
| Critical-rate of rise of off-state | | (dv/dt)c | 10 | | | V/μs | Tj = 125°C | |
| commutation voltageNote5 | | | 1 | _ | _ | | Tj = 150°C | |

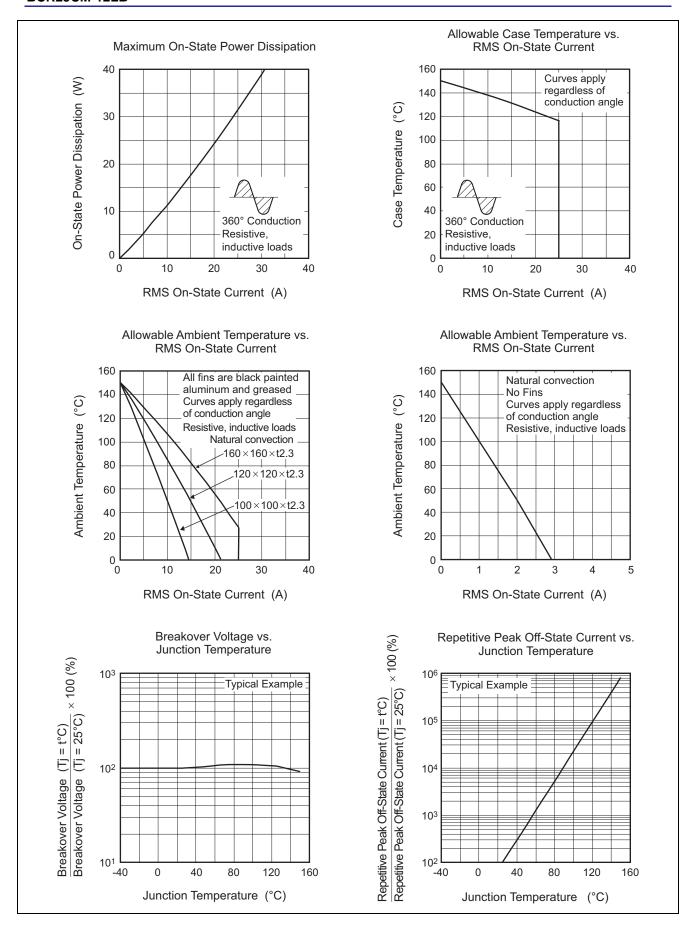
Notes: 1. Gate open.

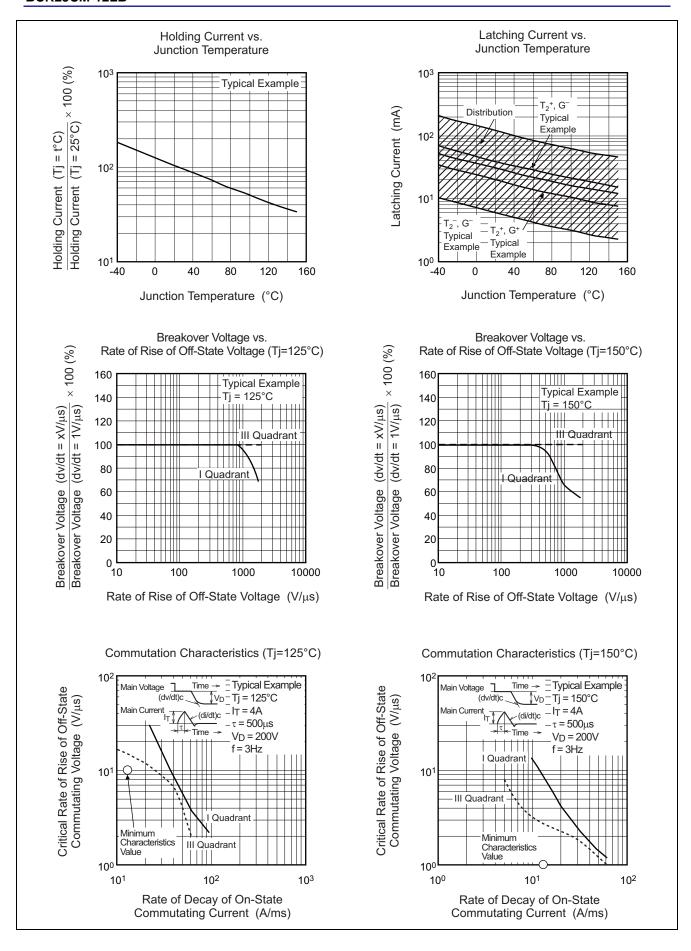
- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. Case temperature is measured at the $T_2\, \text{tab}\,\, 1.5$ mm apart from the molded case.
- 4. The contact thermal resistance $R_{th\;(c\text{-}f)}$ in case of greasing is 1.0°C /W.
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

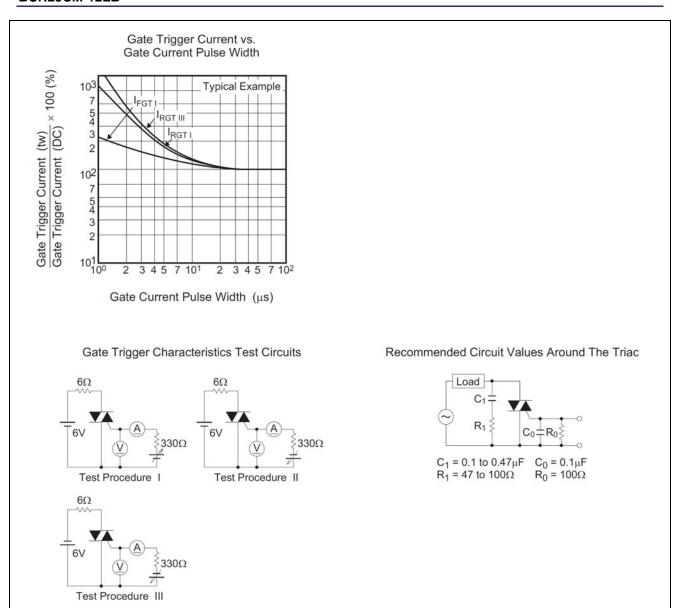
| Test conditions | Commutating voltage and current waveforms |
|----------------------------------------------------------------------|-------------------------------------------|
| | (inductive load) |
| 1. Junction temperature Tj = 125/150°C | Supply Voltage → Time |
| 2. Peak off-state voltage V _D = 400 V | Main Current (di/dt)c → Time |
| 3. Rate of decay of on-state commutating current (di/dt)c = −13 A/ms | Main Voltage Time |

Performance Curves

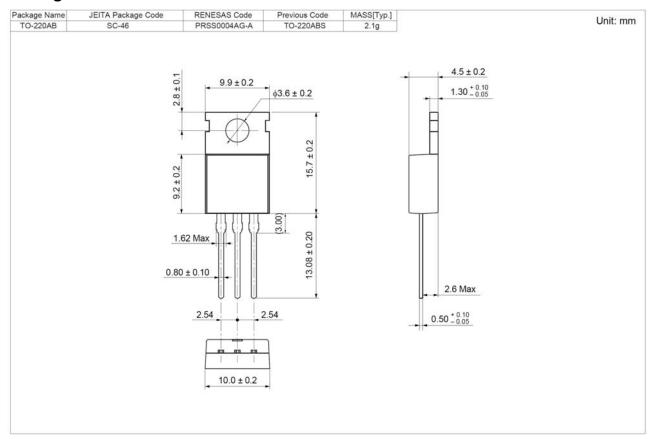








Package Dimensions



Ordering Information

| Orderable Part Number | Packing | Quantity | Remark |
|-----------------------|---------|----------|-----------------------|
| BCR25CM-12LB#BB0 | Tube | 50 pcs. | Straight type |
| BCR25CM-12LB□□#BB0 | Tube | 50 pcs. | □□: Lead forming type |

Note: Please confirm the specification about the shipping in detail.

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